RoHS

HALOGEN

FREE



2 A, 1.2 V, Slew Rate Controlled Load Switch

DESCRIPTION

The SiP32411 is a slew rate controlled load switch that is designed for 1.1 V to 5.5 V operation.

The device guarantees low switch on-resistance at $1.2\ V$ input. It features a controlled soft-on slew rate of typical $150\ \mu s$ that limits the inrush current for designs of capacitive load or noise sensitive loads.

The device features a low voltage control logic interface (On/ Off interface) that can interface with low voltage digital control without extra level shifting circuit. It also integrates an output discharge switch that enables fast shutdown load discharge. When the switch is off, it provides the reverse blocking to prevent high current flowing into the power source.

The SiP32411DN is in TDFN4 package of 1.2 mm by 1.6 mm. It supports over 2 A of continuous current. The SiP32411DR is in SC70-6 package.

FEATURES

- 1.1 V to 5.5 V operation voltage range
- 62 mΩ typical from 2 V to 5 V for SiP32411DN
- 101 m Ω typical from 2 V to 5 V for SiP32411DR
- Low R_{ON} down to 1.2 V
- Slew rate controlled turn-on: 150 µs at 3.6 V
- Fast shutdown load discharge
- Low quiescent current
 1 μA when disabled
 6.7 μA at V_{IN} = 1.2 V
- · Switch off reversed blocking
- Compliant to RoHS Directive 2002/95/EC
- · Halogen-free according to IEC 61249-2-21 definition

APPLICATIONS

- · Cellular phones
- · Portable media players
- · Digital camera
- GPS
- Computers
- · Portable instruments and healthcare devices

TYPICAL APPLICATION CIRCUIT

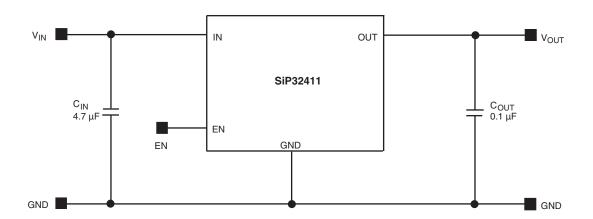


Figure 1 - SiP32411 Typical Application Circuit



| ORDERING INFORMATION | | | | | |
|----------------------|-----------------------|------|--------------------|--|--|
| Temperature Range | Package Marking | | Part Number | | |
| - 40 °C to 85 °C | SC70-6 | MBxx | SiP32411DR-T1-GE3 | | |
| | TDFN4 1.2 mm x 1.6 mm | AEx | SiP32411DNP-T1-GE4 | | |

Notes:

x = Lot Code

GE3 and GE4 denote halogen-free and RoHS compliant

| ABSOLUTE MAXIMUM RATINGS | | | | | |
|-----------------------------------------------------------|------------------------------------------|--------------------------------|------|--|--|
| Parameter | Limit | Unit | | | |
| Supply Input Voltage (V _{IN}) | - 0.3 to 6 | | | | |
| Enable Input Voltage (V _{EN}) | | - 0.3 to 6 | V | | |
| Output Voltage (V _{OUT}) | | - 0.3 to V _{IN} + 0.3 | | | |
| Maximum Continuous Switch Current (L) | SC70-6 package | 1.8 | Α | | |
| Maximum Continuous Switch Current (I _{MAX}) | TDFN4 1.2 mm x 1.6 mm | 2.4 | | | |
| Maximum Pulsed Current (I _{DM}) V _{IN} | SC70-6 package | 2.2 | | | |
| (Pulsed at 1 ms, 10 % Duty Cycle) | TDFN4 1.2 mm x 1.6 mm | 3 | | | |
| ESD Rating (HBM) | 4000 | V | | | |
| Junction Temperature (T _J) | | - 40 to 125 | °C | | |
| Thermal Resistance $(\theta_{IA})^a$ | 6 pin SC70-6 ^b | 240 | °C/W | | |
| memai nesisiance (dja) | 4 pin TDFN4 1.2 mm x 1.6 mm ^c | 170 | | | |
| Power Dissipation /P \a | 6 pin SC70-6 ^b | 230 | mW | | |
| Power Dissipation (P _D) ^a | 4 pin TDFN4 1.2 mm x 1.6 mm ^c | 324 | | | |

Notes:

- a. Device mounted with all leads and power pad soldered or welded to PC board, see PCB layout.
- b. Derate 4.5 mW/°C above T_A = 70 °C, see PCB layout.
- c. Derate 5.9 mW/°C above $T_A = 70$ °C, see PCB layout.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating/conditions for extended periods may affect device reliability.

| RECOMMENDED OPERATING RANGE | | | | |
|----------------------------------------|------------|------|--|--|
| Parameter | Limit | Unit | | |
| Input Voltage Range (V _{IN}) | 1.1 to 5.5 | V | | |
| Operating Temperature Range | - 40 to 85 | °C | | |





| SPECIFICATIONS | | | | | | | |
|------------------------------------|----------------------|-----------------------------------------------------------------------------------------------|---------------------------------------------------------------------------|----------------------------|-------|-------------------|------------------|
| | | Test Conditions Unless Specified V _{IN} = 5.0 V, T _A = -40 °C to 85 °C | | Limits - 40 °C to 85 °C | | | |
| Parameter | Symbol | | ypical values are at T _A = 25 °C) | Min. ^a | Typ.b | Max. ^a | Unit |
| Operating Voltage ^c | V _{IN} | | | 1.1 | - | 5.5 | V |
| | IQ | | V _{IN} = 1.2 V, EN = active | | 6.7 | 14 | μΑ |
| | | | V _{IN} = 1.8 V, EN = active | | 14 | 24 | |
| | | V _{IN} = 2.5 V, EN = active | | - | 25 | 40 | |
| Quiescent Current | | V _{IN} = 3.6 V, EN = active | | - | 40 | 60 | |
| | | V _{IN} = 4.3 V, EN = active | | - | 52 | 75 | |
| | | | V _{IN} = 5.0 V, EN = active | - | 71 | 99 | |
| Off Supply Current | I _{Q(off)} | | EN = inactive, OUT = open | - | - | 1 | 1 |
| Off Switch Current | I _{DS(off)} | | EN = inactive, OUT = GND | - | - | 1 | 1 |
| Reverse Blocking Current | I _{RB} | V _{OU} | $_{T}$ = 5 V, V_{IN} = 1.2 V, V_{EN} = inactive | - | - | 10 | 1 |
| | | | $V_{IN} = 1.2 \text{ V}, I_L = 100 \text{ mA}, T_A = 25 ^{\circ}\text{C}$ | - | 105 | 125 | |
| | | | V _{IN} = 1.8 V, I _L = 100 mA, T _A = 25 °C | - | 101 | 120 | 1 |
| | | 0070.0 | $V_{IN} = 2.5 \text{ V}, I_L = 100 \text{ mA}, T_A = 25 ^{\circ}\text{C}$ | - | 101 | 120 | 1 |
| | | SC70-6 | $V_{IN} = 3.6 \text{ V}, I_L = 100 \text{ mA}, T_A = 25 ^{\circ}\text{C}$ | - | 101 | 120 | 1 |
| | | | $V_{IN} = 4.3 \text{ V}, I_L = 100 \text{ mA}, T_A = 25 ^{\circ}\text{C}$ | - | 101 | 120 | 1 |
| On Basistanas | R _{DS(on)} | | $V_{IN} = 5.0 \text{ V}, I_L = 100 \text{ mA}, T_A = 25 ^{\circ}\text{C}$ | - | 101 | 120 | |
| On-Resistance | | TDFN4 1.2 mm x 1.6 mm | $V_{IN} = 1.2 \text{ V}, I_L = 100 \text{ mA}, T_A = 25 ^{\circ}\text{C}$ | - | 66 | 76 | mΩ |
| | | | V _{IN} = 1.8 V, I _L = 100 mA, T _A = 25 °C | - | 62 | 72 | - - - - |
| | | | $V_{IN} = 2.5 \text{ V}, I_L = 100 \text{ mA}, T_A = 25 ^{\circ}\text{C}$ | - | 62 | 72 | |
| | | | $V_{IN} = 3.6 \text{ V}, I_L = 100 \text{ mA}, T_A = 25 ^{\circ}\text{C}$ | - | 62 | 72 | |
| | | | $V_{IN} = 4.3 \text{ V}, I_L = 100 \text{ mA}, T_A = 25 ^{\circ}\text{C}$ | - | 62 | 72 | |
| | | | $V_{IN} = 5.0 \text{ V}, I_L = 100 \text{ mA}, T_A = 25 ^{\circ}\text{C}$ | - | 62 | 72 | |
| On-Resistance TempCoefficient | TC | | SC70-6 package | | 4300 | - | nnm/°C |
| On-nesistance tempCoemicient | TC _{RDS} | TDFN4 1.2 mm x 1.6 mm package | | - | 3400 | - | ppm/°C |
| | V _{IL} | V _{IN} = 1.2 V | | i | 0.5 | 0.3 | V |
| | | V _{IN} = 1.8 V | | i | 0.72 | 0.4 ^d | |
| EN Input Low Voltage ^c | | V _{IN} = 2.5 V | | i | 0.87 | 0.5 ^d | |
| Liv input Low Voltage | | V _{IN} = 3.6 V | | i | 1.0 | 0.6 ^d | |
| | | V _{IN} = 4.3 V | | i | 1.08 | 0.7 ^d | |
| | | V _{IN} = 5.0 V | | i | 1.15 | 0.8 ^d | |
| EN Input High Voltage ^c | V _{IH} | V _{IN} = 1.2 V | | 0.9 ^d | 0.54 | - | |
| | | V _{IN} = 1.8 V | | 1.2 ^d | 0.78 | - | |
| | | V _{IN} = 2.5 V | | 1.4 ^d | 0.96 | - | |
| | | V _{IN} = 3.6 V | | 1.6 ^d | 1.2 | - | |
| | | V _{IN} = 4.3 V | | 1.7 ^d | 1.32 | - | |
| | | V _{IN} = 5.0 V | | 1.8 | 1.45 | - | |
| EN Input Leakage | I _{SINK} | V _{EN} = 5.5 V | | - 1 | - | 1 | μΑ |
| Output Pulldown Resistance | R _{PD} | | EN = inactive, T _A = 25 °C | - | 217 | 280 | Ω |
| Output Turn-On Delay Time | t _{d(on)} | | | ı | 140 | 210 | |
| Output Turn-On Rise Time | t _(on) | $V_{IN} = 3.6 \text{ V}, R_{LOAD} = 10 \Omega, T_A = 25 ^{\circ}\text{C}$ | | 80 | 150 | 220 | μs |
| Output Turn-Off Delay Time | t _{d(off)} | | | - | 0.27 | 1 | |

Notes:

- a. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum.
- b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- c. For $V_{\mbox{\scriptsize IN}}$ outside this range consult typical EN threshold curve.
- d. Not tested, guarantee by design.

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PIN CONFIGURATION

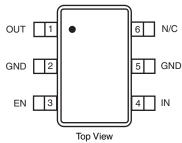


Figure 2 - SC70-6 Package

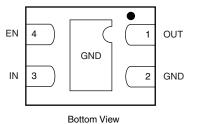


Figure 3 - TDFN4 1.2 mm x 1.6 mm Package

| PIN DESCRIPTION | | | | | |
|-----------------|-------|------|-------------------------------------------------------------------------------------------------------|--|--|
| Pin Number | | | | | |
| SC70-6 | TDFN4 | Name | Function | | |
| 4 | 3 | IN | This pin is the n-channel MOSFET drain connection. Bypass to ground through a 2.2 μF capacitor. | | |
| 2, 5 | 2 | GND | Ground connection | | |
| 3 | 4 | EN | Enable input | | |
| 1 | 1 | OUT | This pin is the n-channel MOSFET source connection. Bypass to ground through a 0.1 μ F capacitor. | | |

TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

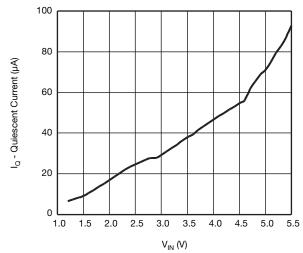


Figure 4 - Quiescent Current vs. Input Voltage

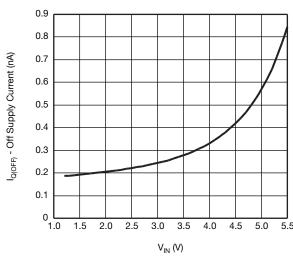


Figure 6 - Off Supply Current vs. Input Voltage

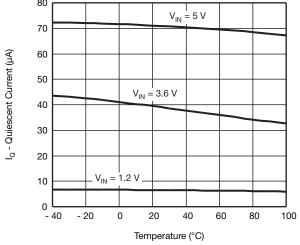


Figure 5 - Quiescent Current vs. Temperature

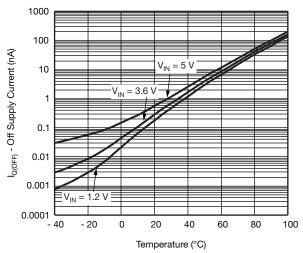


Figure 7 - Off Supply Current vs. Temperature



TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

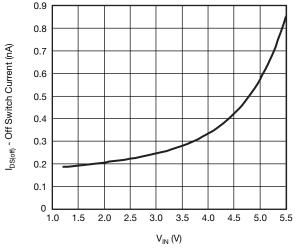


Figure 8 - Off Switch Current vs. Input Voltage

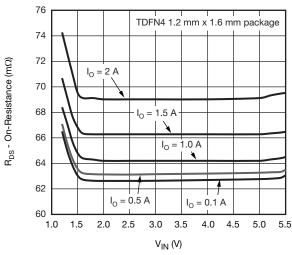


Figure 10 - R_{DS(on)} vs. V_{IN} for TDFN4 package

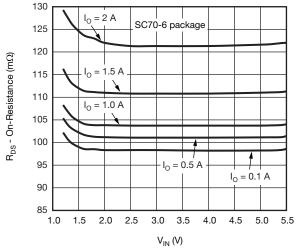


Figure 12 - R_{DS(on)} vs. V_{IN} for SC70-6 package

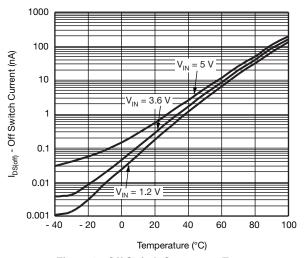


Figure 9 - Off Switch Current vs. Temperature

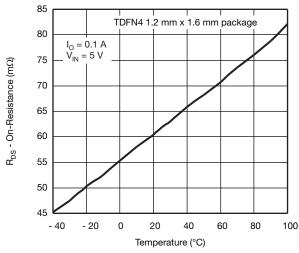


Figure 11 - $R_{DS(on)}$ vs. Temperature for TDFN4 package

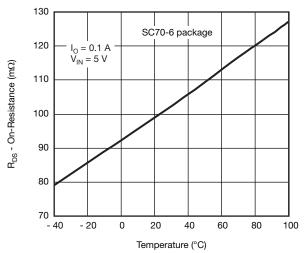


Figure 13 - $R_{DS(on)}$ vs. Temperature for SC70-6 package

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TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

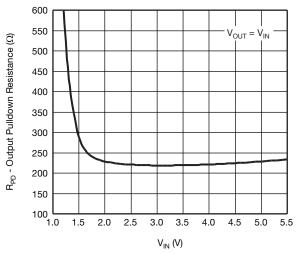


Figure 14 - Output Pull Down vs. Input Voltage

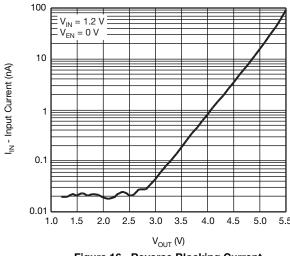


Figure 16 - Reverse Blocking Current vs. Output Voltage

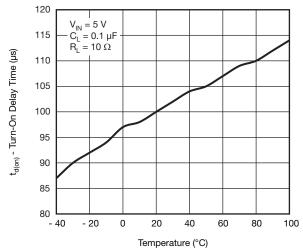


Figure 18 - Turn-On Delay Time vs. Temperature

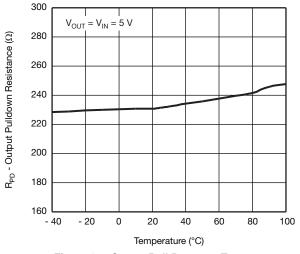


Figure 15 - Output Pull Down vs. Temperature

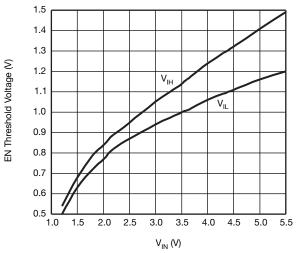


Figure 17 - EN Threshold Voltage vs. Input Voltage

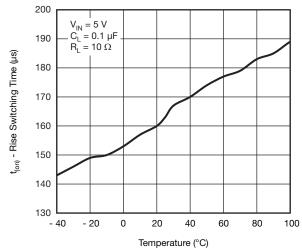


Figure 19 - Rise Time vs. Temperature



TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

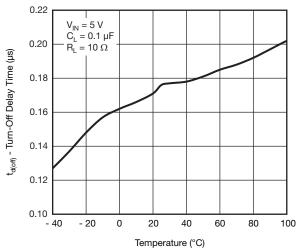


Figure 20 - Turn-Off Delay Time vs. Temperature

TYPICAL WAVEFORMS

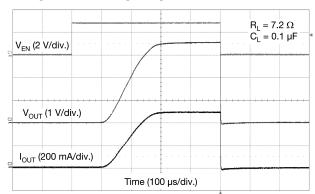


Figure 21 - Switching $(V_{IN} = 3.6 \text{ V})$

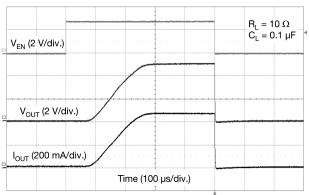


Figure 23 - Switching $(V_{IN} = 5 V)$

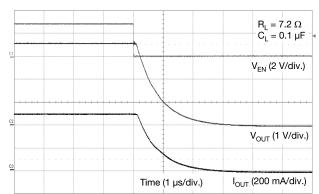


Figure 22 - Turn-Off (V_{IN} = 3.6 V)

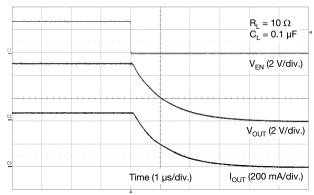


Figure 24 - Turn-Off (V_{IN} = 5 V)

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BLOCK DIAGRAM

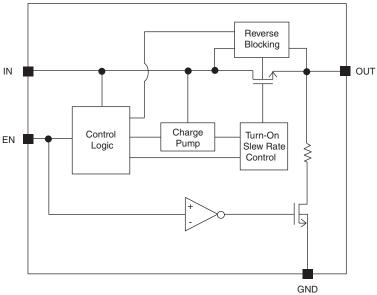
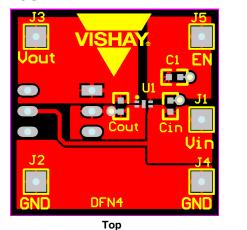
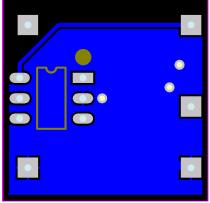


Figure 25 - Functional Block Diagram

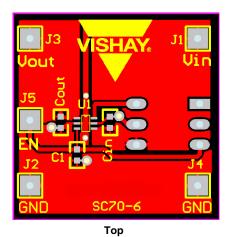
PCB LAYOUT

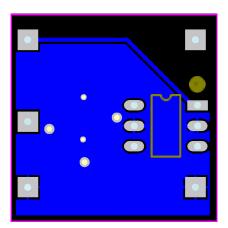




Bottom

Figure 26 - PCB Layout for TDFN4 1.2 mm x 1.6 mm (board size: 1 inch x 1 inch)





Bottom

Figure 27 - PCB Layout for SC70-6 (board size: 1 inch x 1 inch)



DETAILED DESCRIPTION

SiP32411 is an n-channel power MOSFET designed as high side load switch with slew rate control to prevent in-rush current. Once enable the device charge pumps the gate of the power MOSFET to 5 V gate to source voltage while controlling the slew rate of the turn on time. The mostly constant gate to source voltage keeps the on resistance low through out the input voltage range. When disable, the output discharge circuit turns on to help pull the output voltage to ground more quickly. Also in disable mode, the reverse blocking circuit is activated to prevent current from going back to the input in case the output voltage is higher than the input voltage. Input voltage is needed for the reverse blocking circuit to work properly, it can be as low as V_{IN(min)}.

APPLICATION INFORMATION

Input Capacitor

While a bypass capacitor on the input is not required, a 2.2 μF or larger capacitor for C_{IN} is recommended in almost all applications. The bypass capacitor should be placed as physically close as possible to the SiP32411 to be effective in minimizing transients on the input. Ceramic capacitors are recommended over tantalum because of their ability to withstand input current surges from low impedance sources such as batteries in portable devices.

Output Capacitor

A 0.1 μF capacitor or larger across V_{OUT} and GND is recommended to insure proper slew operation. C_{OUT} may be increased without limit to accommodate any load transient condition with only minimal affect on the SiP32411 turn on slew rate time. There are no ESR or capacitor type requirement.

Enable

The EN pin is compatible with both TTL and CMOS logic voltage levels.

Protection Against Reverse Voltage Condition

The SiP32411 contains a reverse blocking circuitry to protect the current from going to the input from the output in case where the output voltage is higher than the input voltage when the main switch is off. A supply voltage as low as the minimum required input voltage is necessary for this circuitry to work properly.

Thermal Considerations

The SiP32411 is designed to maintain a constant output load current. Due to physical limitations of the layout and assembly of the device the maximum switch current is 1.8 A for SC70-6 package and 2.4 A for TDFN4 package, as stated in the Absolute Maximum Ratings table. However, another limiting characteristic for the safe operating load current is the thermal power dissipation of the package. To obtain the highest power dissipation (and a thermal resistance of

240 °C/W for SC70-6 and 170 °C/W for TDFN4) the power pad of the device should be connected to a heat sink on the printed circuit board.

The maximum power dissipation in any application is dependant on the maximum junction temperature, $T_{J(MAX)}$ = 125 °C, the junction-to-ambient thermal resistance for the TDFN4 1.2 mm x 1.6 mm package, θ_{J-A} = 170 °C/W, and the ambient temperature, T_A , which may be formulaically expressed as:

P (max.) =
$$\frac{T_J (max.) - T_A}{\theta_{J-A}} = \frac{125 - T_A}{170}$$

It then follows that, assuming an ambient temperature of 70 $^{\circ}$ C, the maximum power dissipation will be limited to about 324 mW.

So long as the load current is below the 2.0 A limit, the maximum continuous switch current becomes a function two things: the package power dissipation and the $R_{DS(ON)}$ at the ambient temperature.

As an example let us calculate the worst case maximum load current at $T_A=70~^{\circ}\text{C}$. The worst case $R_{DS(ON)}$ at 25 $^{\circ}\text{C}$ occurs at an input voltage of 1.2 V and is equal to 75 m Ω . The $R_{DS(ON)}$ at 70 $^{\circ}\text{C}$ can be extrapolated from this data using the following formula:

 $R_{DS(ON)}$ (at 70 °C) = $R_{DS(ON)}$ (at 25 °C) x (1 + T_C x $\Delta T)$ Where T_C is 3400 ppm/°C. Continuing with the calculation we have

 $R_{DS(ON)}$ (at 70 °C) = 75 m Ω x (1 + 0.0034 x (70 °C - 25 °C)) = 86.5 m Ω

The maximum current limit is then determined by

$$I_{LOAD}$$
 (max.) $<\sqrt{\frac{P \text{ (max.)}}{R_{DS(ON)}}}$

which in case is 1.94 A. Under the stated input voltage condition, if the 1.94 A current limit is exceeded the internal die temperature will rise and eventually, possibly damage the device.

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